Memory Microcircuit - Page 1 of 1



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## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## End Application:

4920-00-216-9141

#### Features Provided:

Bipolar and high speed and high reliability and low current and high current and schottky and electrically alterable

### Inclosure Configuration:

Dual-in-line

### **Current Rating Per Characteristic:**

-30.00 milliamperes collector cutoff current, dc, with specified resistance between base and emitter microamperes and 5.00 milliamperes reverse current, dc microamperes

Terminal Surface Treatment:

Solder

**Product Name:** 

Microcircuit memory, 512 x 4 bit bipolar prom

Voltage Rating And Type Per Characteristic:

-0.5 volts total supply and 7.0 volts total supply

**Time Rating Per Chacteristic:** 

40.00 nanoseconds access

Memory Device Type:

Eeprom

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). And 96906-mil-std-130 standard (includes industry or association standards, individual manufactureer standards, etc.). And 81349-mil-i-43553 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

**Terminal Type And Quantity:** 

16 printed circuit

**Purchase Description Identification:** 

S7040-mc8304419-0

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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